



Features

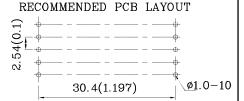
- Low power consumption
- ullet Robust package
- I.C. Compatible
- Standard configuration: Gray face w/ white segments

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- Optional black face provides superior color contrast
- RoHS Compliant

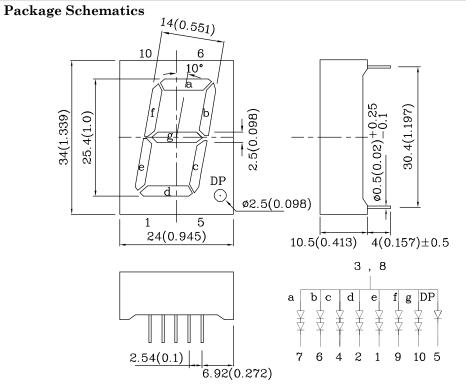








ATTENTION OBSERVE PRECAUTIONS FOR HANDLING ELECTROSTATIC DISCHARGE SENSITIVE DEVICES



Notes.

- 1. All dimensions are in millimeters (inches), Tolerance is \pm 0.25(0.01")unless otherwise noted.
- 2. Specifications are subject to change without notice.

Absolute Maximum Ratings (T _A =25°C)	DGK (InGaN)	Unit		
Reverse Voltage (Per Chip)	V_{R}	5	V	
Forward Current (Dp)	I_{F}	25 (25)	mA	
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width (Dp)	i _{FS}	150 (150)	mA	
Power Dissipation (Per Chip)	P_{D}	102.5	mW	
Operating Temperature	T_{A}	-40 ~ +85	°C	
Storage Temperature	Tstg	-40 ~ +85		
Electrostatic Discharge Threshol (HBM)	450	V		
Lead Solder Temperature [2mm Below Package Base]	260°C For 3~5 Seconds			

Operating Characteristics (T _A =25°C)		DGK (InGaN)	Unit
Forward Voltage (Typ.) (Dp) (I _F =10mA)	V_{F}	6 (3)	V
Forward Voltage (Max.) (Dp) (I _F =10mA)	V_{F}	8.2 (4.1)	V
Reverse Current (Max.) (Per Chip) $(V_R=5V)$	I_R	50	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) $(I_F=10\text{mA})$	λP	515*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) $(I_F=10\text{mA})$	λD	525*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =10mA)	Δλ	35	nm
Capacitance (Typ.) (V _F =0V, f=1MHz)	С	45	pF

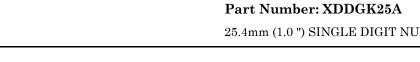
Part Number	Emitting Color	Emitting Material	Luminous Intensity CIE127-2007* (IF=10mA) ucd		Wavelength CIE127-2007* nm λP	Description
			min.	typ.		
XDDGK25A	Green	InGaN	255000 88000*	789990 259990*	515 *	Common Anode, Rt.Hand Decimal

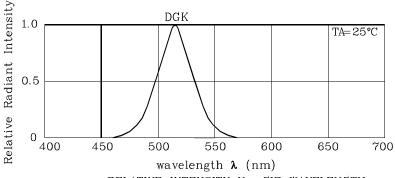
^{*}Luminous intensity value and wavelength are in accordance with CIE127-2007 standards.

Jan 20,2014

XDSB7710 V1-X Layout: Maggie L.

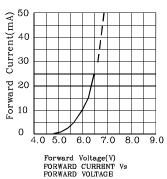


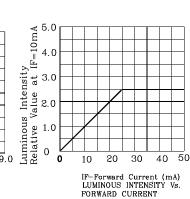


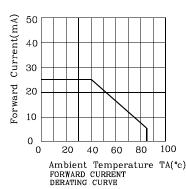


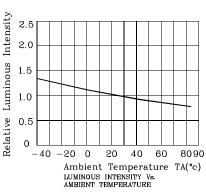
RELATIVE INTENSITY Vs. CIE WAVELENGTH

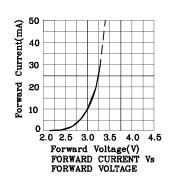
❖ DGK

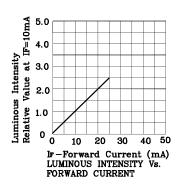


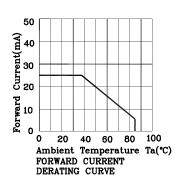


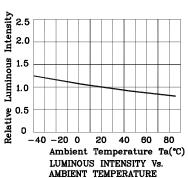




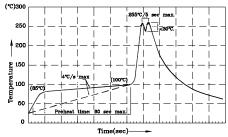








Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux, or wavelength),

the typical accuracy of the sorting process is as follows:

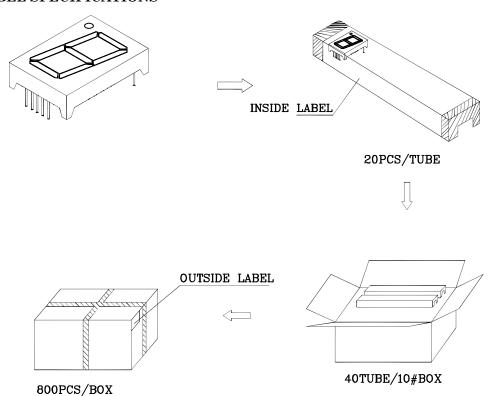
- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V

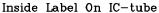
Note: Accuracy may depend on the sorting parameters.

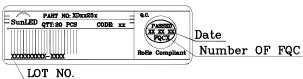


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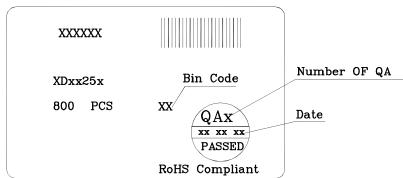
PACKING & LABEL SPECIFICATIONS







Outside Label On Box



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- 2. Contents within this document are subject to improvement and enhancement changes without notice.
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- 5. The contents within this document may not be altered without prior consent by SunLED.
- $6. \ Additional\ technical\ notes\ are\ available\ at\ \underline{http://www.SunLEDusa.com/TechnicalNotes.asp}$

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